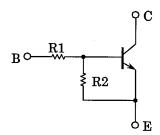
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

# RN1107, RN1108, RN1109

Switching, Inverter Circuit, Interface Circuit and Driver Circuit Applications

- With built-in bias resistors.
- Simplified circuit design
- Reduced number of parts and simplified manufacturing process
- Complementary to RN2107 to 2109

## **Equivalent Circuit and Bias Resistor Values**



| Type No. | R1 (kΩ) | R2 (kΩ) |
|----------|---------|---------|
| RN1107   | 10      | 47      |
| RN1108   | 22      | 47      |
| RN1109   | 47      | 22      |

# 1. BASE 2. EMITTER SSM 3. COLLECTOR JEDEC — JEITA — TOSHIBA 2-2H1A

Weight: 2.4mg (typ.)

# Absolute Maximum Ratings (Ta = 25°C)

| Characteristi               | Symbol         | Rating           | Unit       |    |  |
|-----------------------------|----------------|------------------|------------|----|--|
| Collector-base voltage      | RN1107 to 1109 | $V_{CBO}$        | 50         | V  |  |
| Collector-emitter voltage   | RN1107 to 1109 | V <sub>CEO</sub> | 50         | V  |  |
|                             | RN1107         |                  | 6          | ٧  |  |
| Emitter-base voltage        | RN1108         | $V_{EBO}$        | 7          |    |  |
|                             | RN1109         |                  | 15         |    |  |
| Collector current           | RN1107 to 1109 | IC               | 100        | mA |  |
| Collector power dissipation | RN1107 to 1109 | PC               | 100        | mW |  |
| Junction temperature        | RN1107 to 1109 | Tj               | 150        | °C |  |
| Storage temperature range   | RN1107 to 1109 | T <sub>stg</sub> | -55 to 150 | °C |  |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

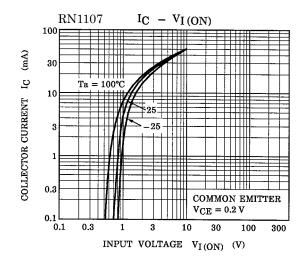
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

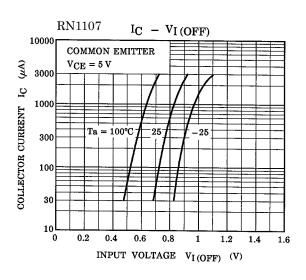


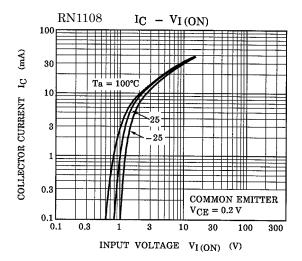
# Electrical Characteristics (Ta = 25°C)

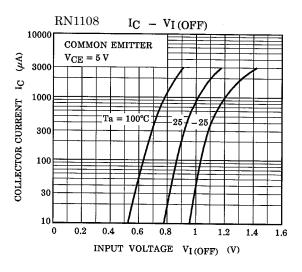
| Characteri                           | stic           | Symbol                | Test<br>Circuit | Test Condition   | Min   | Тур.  | Max   | Unit |
|--------------------------------------|----------------|-----------------------|-----------------|--|-------|-------|-------|------|
| Collector cut off current            | RN1107 to 1109 | I <sub>CBO</sub>      | _               | V <sub>CB</sub> = 50 V, I <sub>E</sub> = 0               | _     | _     | 100   | nA   |
|                                      |                | ICEO                  | _               | V <sub>CE</sub> = 50 V, I <sub>B</sub> = 0               | _     | _     | 500   | nA   |
|                                      | RN1107         |                       | _               | V <sub>EB</sub> = 6 V, I <sub>C</sub> = 0                | 0.081 | _     | 0.15  |      |
| Emitter cut-off current              | RN1108         | I <sub>EBO</sub>      | _               | V <sub>EB</sub> = 7 V, I <sub>C</sub> = 0                | 0.078 | _     | 0.145 | mA   |
|                                      | RN1109         |                       | _               | V <sub>EB</sub> = 15 V, I <sub>C</sub> = 0               | 0.167 | _     | 0.311 |      |
|                                      | RN1107         |                       | _               |  | 80    | _     | _     |      |
| DC current gain                      | RN1108         | h <sub>FE</sub>       | _               | V <sub>CE</sub> = 5 V, I <sub>C</sub> = 10 mA            | 80    | _     | _     | _    |
|                                      | RN1109         |                       | _               |  | 70    | _     | _     |      |
| Collector-emitter saturation voltage | RN1107 to 1109 | V <sub>CE</sub> (sat) | _               | I <sub>C</sub> = 5 mA, I <sub>B</sub> = 0.25 mA          | _     | 0.1   | 0.3   | V    |
|                                      | RN1107         |                       | _               |  | 0.7   | _     | 1.8   |      |
| Input voltage (ON)                   | RN1108         | V <sub>I (ON)</sub>   | _               | V <sub>CE</sub> = 0.2 V, I <sub>C</sub> = 5 mA           | 1.0   | _     | 2.6   | ٧    |
|                                      | RN1109         |                       | _               |  | 2.2   | _     | 5.8   |      |
|                                      | RN1107         |                       | _               |  | 0.5   | _     | 1.0   |      |
| Input voltage (OFF)                  | RN1108         | V <sub>I (OFF)</sub>  | _               | V <sub>CE</sub> = 5 V, I <sub>C</sub> = 0.1 mA           | 0.6   | _     | 1.16  | V    |
|                                      | RN1109         |                       | _               |  | 1.5   | _     | 2.6   |      |
| Transition frequency                 | RN1107 to 1109 | f <sub>T</sub>        | _               | V <sub>CE</sub> =10 V, I <sub>C</sub> = 5 mA             | _     | 250   | _     | MHz  |
| Collector output capacitance         | RN1107 to 1109 | C <sub>ob</sub>       | _               | V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0,<br>f = 1 MHz | _     | 3     | 6     | pF   |
|                                      | RN1107         |                       | _               |  | 7     | 10    | 13    |      |
| Input Resistor                       | RN1108         | R1                    | _               | _  | 15.4  | 22    | 28.6  | kΩ   |
|                                      | RN1109         |                       | _               |  | 32.9  | 47    | 61.1  |      |
|                                      | RN1107         |                       | _               |  | 0.191 | 0.213 | 0.232 |      |
| Resistor Ratio                       | RN1108         | R1/R2                 | _               | 1 –  | 0.421 | 0.468 | 0.515 | _    |
|                                      | RN1109         |                       | _               |  | 1.92  | 2.14  | 2.35  |      |

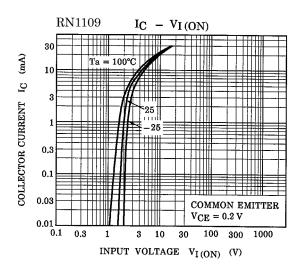
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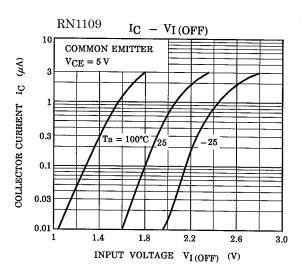


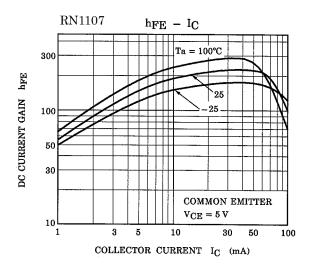


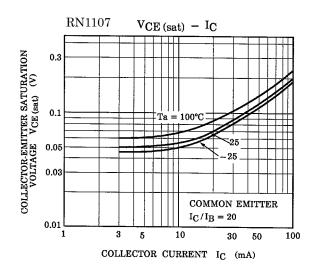


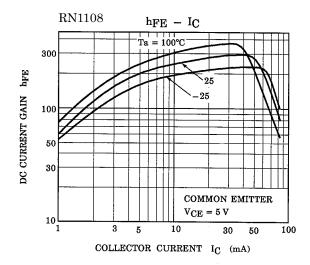


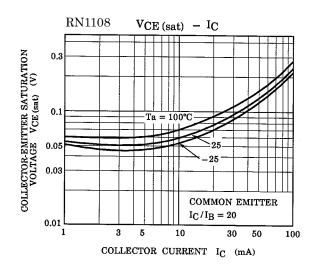
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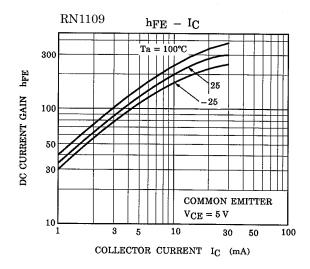


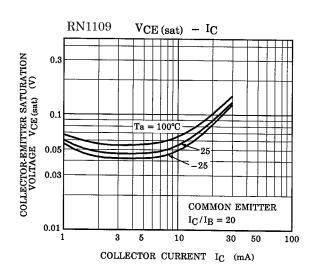












| Type Name | Marking        |
|-----------|----------------|
| RN1107    | Type Name  X H |
| RN1108    | Type Name      |
| RN1109    | Type Name      |

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5

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6